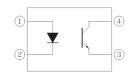


DATASHEET

4 PIN DIP LOW INPUT PHOTOTRANSISTOR PHOTOCOUPLER EL8171-G Series



Schematic



Features:

- Current transfer ratio (CTR: 100~350% at I_F = 0.5mA, V_{CE} = 5V)
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62 mm
- Operating temperature up to +100°C
- Compliance with EU REACH
- Compliance Halogen Free (Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)
- •The product itself will remain within RoHS compliant version
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- CQC approved

Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

Description

The EL8171-G series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector with green compound.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- · System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances



Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	10	mA
	Reverse voltage	V_{R}	6	V
	Power dissipation	P_{D}	20	mW
Output	Power dissipation	Pc	150	mW
	Collector current	I _C	50	mA
	Collector-Emitter voltage	V _{CEO}	70	V
	Emitter-Collector voltage	V _{ECO}	6	V
Total power d	issipation	P _{TOT}	170	mW
Isolation volta	age *1	V _{ISO}	5000	V rms
Operating ten	nperature	T _{OPR}	-30 ~ +100	°C
Storage temperature		T _{STG}	-55 ~ +125	°C
Soldering Temperature*2		T _{SOL}	260	°C

Notes:

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward Voltage	V _F	-	1.2	1.4	V	I _F = 10mA
Reverse Current	I_{R}	-	-	10	μA	V _R = 4V
Input capacitance	C _{in}	-	-	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	V _{CE} = 20V, I _F = 0mA
Collector-Emitter breakdown voltage	BV _{CEO}	70	-	-	V	I _C = 0.1mA
Emitter-Collector breakdown voltage	BV _{ECO}	6	-	-	V	I _E = 0.1mA

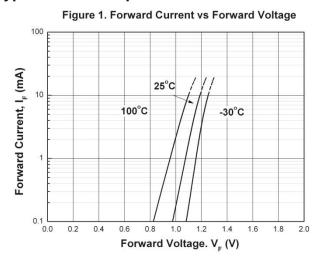
Transfer Characteristics

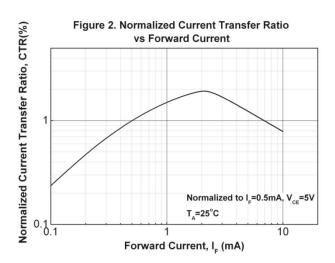
Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	CTR	100		350	%	$I_F = 0.5 \text{mA}, V_{CE} = 5 \text{V}$
Collector-Emitter saturation voltage	V _{CE(sat)}	-		0.2	V	$I_F = 10 \text{mA}$, $I_C = 1 \text{mA}$
Isolation resistance	R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.
Floating capacitance	C_{IO}	-	-	1.0	pF	$V_{IO} = 0$, $f = 1MHz$
Cut-off frequency	fc	-	80	-	kHz	$V_{CE} = 5V$, $I_C = 2mA$ $R_L = 100\Omega$, -3dB
Rise time	t _r	-	-	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time	t_f	-	-	18	μs	$R_L = 100\Omega$

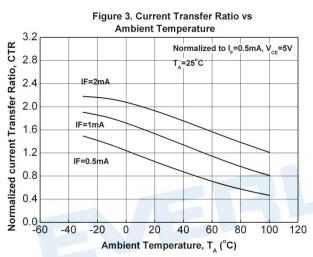
^{*} Typical values at T_a = 25°C

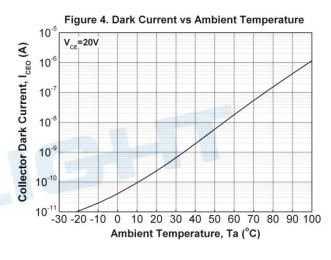


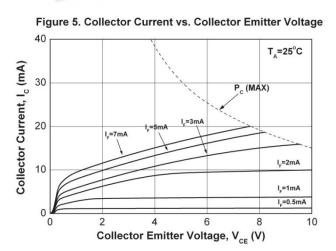
Typical Electro-Optical Characteristics Curves

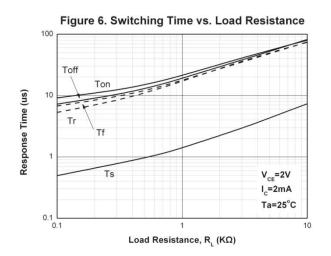












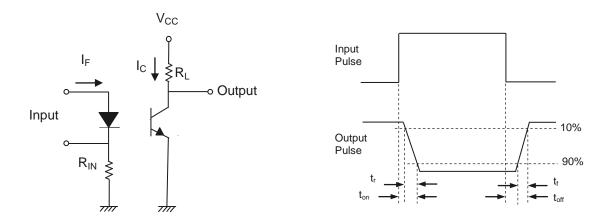


Figure 7. Switching Time Test Circuit & Waveforms





Order Information

Part Number

EL8171X(Z)-VG

Note

X = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB, TU, TD or none)

V = VDE safety (optional)

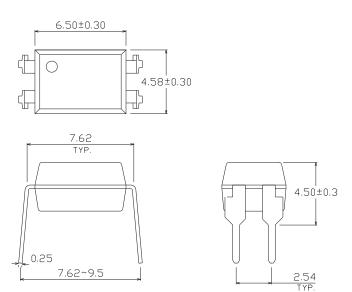
G = Halogens free

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

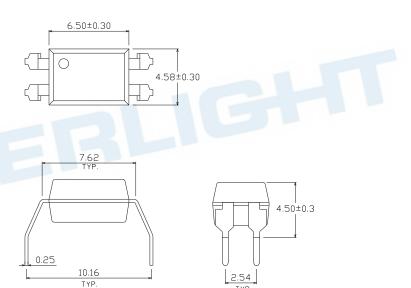


Package Dimension (Dimensions in mm)

Standard DIP Type

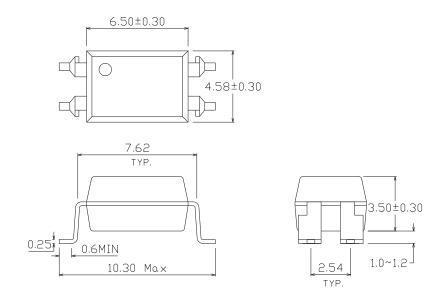


Option M Type

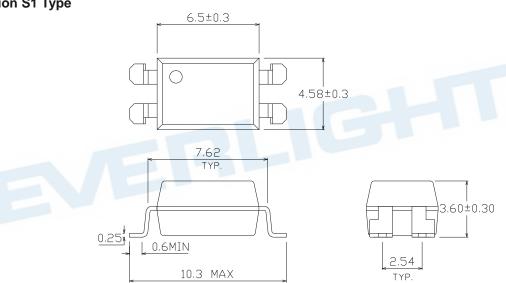




Option S Type

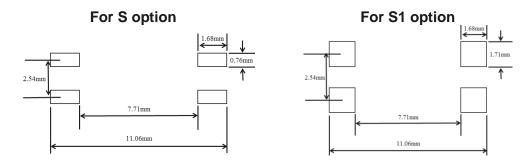


Option S1 Type





Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

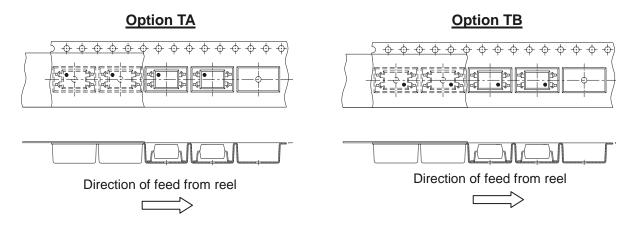


Notes

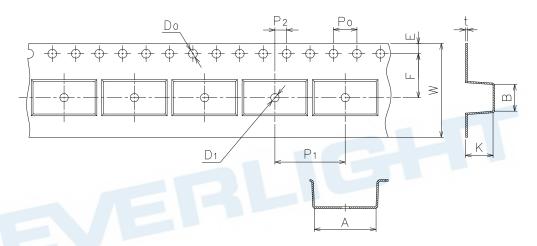
EL	denotes EVERLIGHT
8171	denotes Device Number
G	denotes Green part
Υ	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE optional



Tape & Reel Packing Specifications



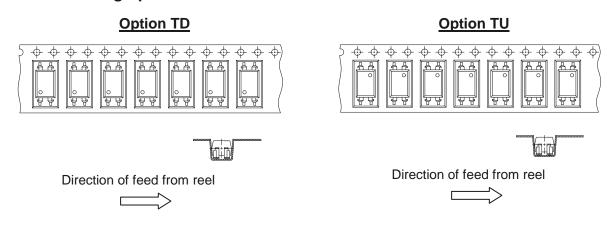
Tape dimensions



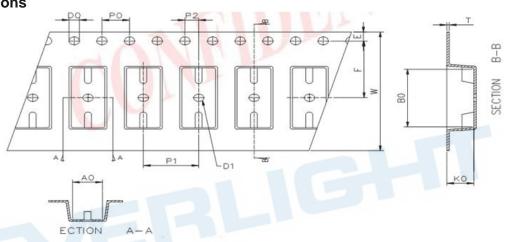
Dimension No.	Α	В	Do	D1	E	F
Dimension (mm) S	10.7±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension (mm) S1	10.7±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	К
Dimension (mm) S	4.0±0.1	12.0±0.1	2.0±0.1	0.4±0.1	16.0±0.3	4.75±0.1
Dimension (mm) S1	4.0±0.1	12.0±0.1	2.0±0.1	0.4±0.1	16.0±0.3	3.90±0.1



Tape & Reel Packing Specifications



Tape dimensions



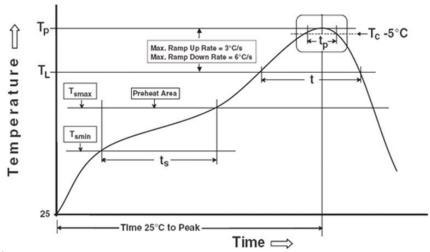
Dimension No.	Ao	Во	Do	D1	E	F
Dimension(mm)	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension(mm)	4.00±0.1	8.00±0.1	2.00±0.1	0.40±0.1	16.00±0.3	4.60±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin}) 150 °C Temperature max (T_{smax}) 200 °C

Time (Tsmin to Tsmax) (ts) 60-120 seconds

Average ramp-up rate (Tsmax to Tp) 3 °C/second max

Other

Liquidus Temperature (T_L)

Time above Liquidus Temperature (t L)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: T_P - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

217 °C

60-100 sec

260°C

30 s

6°C /second max

8 minutes max

3 times



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